

CSD25483F4 20 V P-Channel FemtoFET™ MOSFET

1 Features

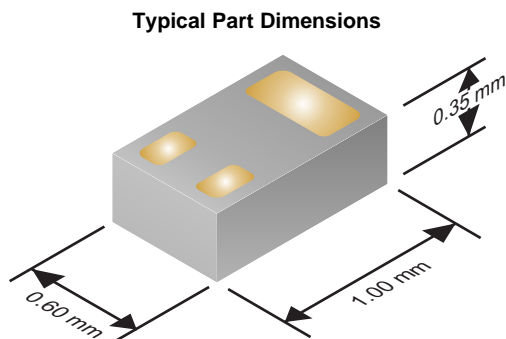
- Ultra-Low On-Resistance
- Ultra-Low Q_g and Q_{gd}
- High Operating Drain Current
- Ultra-Small Footprint (0402 Case Size)
 - 1.0 mm × 0.6 mm
- Ultra-Low Profile
 - 0.35 mm Max Height
- Integrated ESD Protection Diode
 - Rated >4 kV HBM
 - Rated >2 kV CDM
- Lead and Halogen Free
- RoHS Compliant

2 Applications

- Optimized for load Switch Applications
- Optimized for General Purpose Switching Applications
- Battery Applications
- Handheld and Mobile Applications

3 Description

This 210 mΩ, 20 V P-Channel FemtoFET™ MOSFET is designed and optimized to minimize the footprint in many handheld and mobile applications. This technology is capable of replacing standard small signal MOSFETs while providing at least a 60% reduction in footprint size.



Product Summary

$T_A = 25^\circ\text{C}$		TYPICAL VALUE		UNIT
V_{DS}	Drain-to-Source Voltage	–20		V
Q_g	Gate Charge Total (–4.5 V)	959		pC
Q_{gd}	Gate Charge Gate-to-Drain	161		pC
$R_{DS(on)}$	Drain-to-Source On-Resistance	$V_{GS} = -1.8\text{ V}$	530	mΩ
		$V_{GS} = -2.5\text{ V}$	338	mΩ
		$V_{GS} = -4.5\text{ V}$	210	mΩ
$V_{GS(th)}$	Threshold Voltage	–0.95		V

Ordering Information⁽¹⁾

Device	Qty	Media	Package	Ship
CSD25483F4	3000	7-Inch Reel	Femto (0402) 1.0 mm × 0.6 mm Land Grid Array (LGA)	Tape and Reel
CSD25483F4T	250			

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Absolute Maximum Ratings

$T_A = 25^\circ\text{C}$		VALUE	UNIT
V_{DS}	Drain-to-Source Voltage	–20	V
V_{GS}	Gate-to-Source Voltage	–12	V
I_D	Continuous Drain Current ⁽¹⁾	–1.6	A
I_{DM}	Pulsed Drain Current ⁽²⁾	–6.5	A
I_G	Continuous Gate Clamp Current	–35	mA
	Pulsed Gate Clamp Current ⁽²⁾	–350	
P_D	Power Dissipation ⁽¹⁾	500	mW
$V_{(ESD)}$	Human Body Model (HBM)	4	kV
	Charged Device Model (CDM)	2	kV
T_J , T_{stg}	Operating Junction and Storage Temperature Range	–55 to 150	°C

(1) Typical $R_{\theta JA} = 85^\circ\text{C/W}$ on 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 0.06-inch (1.52-mm) thick FR4 PCB.

(2) Pulse duration $\leq 300\ \mu\text{s}$, duty cycle $\leq 2\%$

Top View

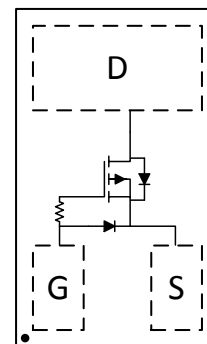


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4 Revision History

Changes from Revision C (July 2014) to Revision D Page

- Corrected timing V_{DS} to read -10 V **3**

Changes from Revision B (February 2014) to Revision C Page

- Corrected capacitance units to read pF in [Figure 5](#) **5**

Changes from Revision A (December 2013) to Revision B Page

- Updated lead and halogen free in features **1**
- Added I_G parameter **1**
- Lowered I_{DSS} limit **3**
- Lowered I_{GSS} limit **3**

Changes from Original (October 2013) to Revision A Page

- Fixed resistance typo **1**
- Added small reel **1**

5 Specifications

5.1 Electrical Characteristics

(T_A = 25°C unless otherwise stated)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC CHARACTERISTICS						
B _V DSS	Drain-to-Source Voltage	V _{GS} = 0 V, I _{DS} = -250 μA	-20			V
I _{DSS}	Drain-to-Source Leakage Current	V _{GS} = 0 V, V _{DS} = -16 V			-100	nA
I _{GSS}	Gate-to-Source Leakage Current	V _{DS} = 0 V, V _{GS} = -12 V			-50	nA
V _{GS(th)}	Gate-to-Source Threshold Voltage	V _{DS} = V _{GS} , I _{DS} = -250 μA	-0.70	-0.95	-1.2	V
R _{DS(on)}	Drain-to-Source On-Resistance	V _{GS} = -1.8 V, I _{DS} = -0.1 A		530	1070	mΩ
		V _{GS} = -2.5 V, I _{DS} = -0.5 A		338	390	mΩ
		V _{GS} = -4.5 V, I _{DS} = -0.5 A		210	245	mΩ
		V _{GS} = -8 V, I _{DS} = -0.5 A		175	205	mΩ
g _{fs}	Transconductance	V _{DS} = -10 V, I _{DS} = -0.5 A		1.4		S
DYNAMIC CHARACTERISTICS						
C _{iss}	Input Capacitance	V _{GS} = 0 V, V _{DS} = -10 V, f = 1 MHz		198		pF
C _{oss}	Output Capacitance			82		pF
C _{rss}	Reverse Transfer Capacitance			5.8		pF
R _G	Series Gate Resistance			20		Ω
Q _g	Gate Charge Total (4.5 V)	V _{DS} = -10 V, I _{DS} = -0.5 A		959		pC
Q _{gd}	Gate Charge Gate-to-Drain			160		pC
Q _{gs}	Gate Charge Gate-to-Source			252		pC
Q _{g(th)}	Gate Charge at V _{th}			122		pC
Q _{oss}	Output Charge		V _{DS} = -10 V, V _{GS} = 0 V		1081	
t _{d(on)}	Turn On Delay Time	V _{DS} = -10 V, V _{GS} = -4.5 V, I _{DS} = -0.5 A, R _G = 2 Ω		4.3		ns
t _r	Rise Time			3.7		ns
t _{d(off)}	Turn Off Delay Time			17.4		ns
t _f	Fall Time			7		ns
DIODE CHARACTERISTICS						
V _{SD}	Diode Forward Voltage	I _{SD} = -0.5 A, V _{GS} = 0 V		-0.75		V
Q _{rr}	Reverse Recovery Charge	V _{DS} = -10 V, I _F = -0.5 A, di/dt = 100 A/μs		1060		pC
t _{rr}	Reverse Recovery Time			7.5		ns

5.2 Thermal Information

(T_A = 25°C unless otherwise stated)

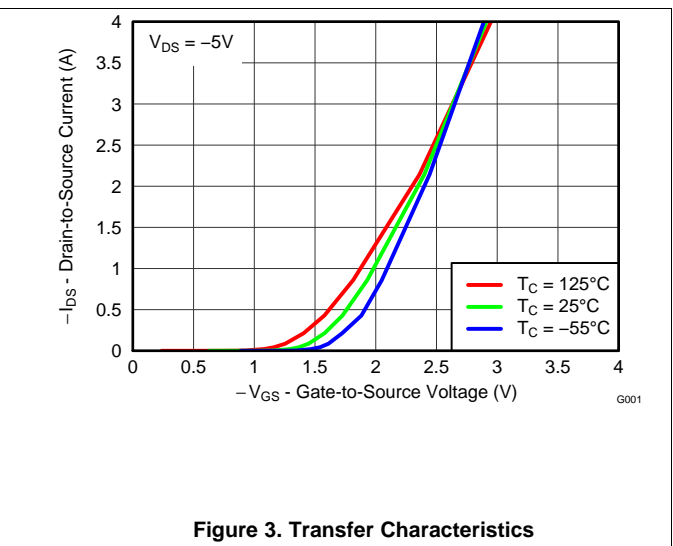
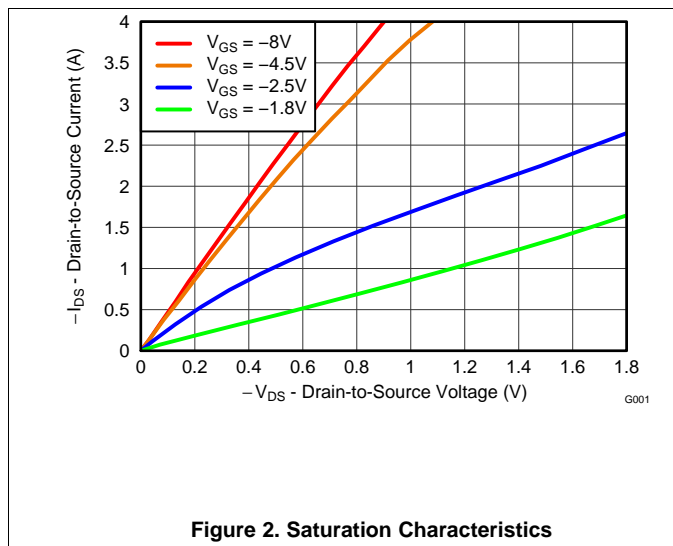
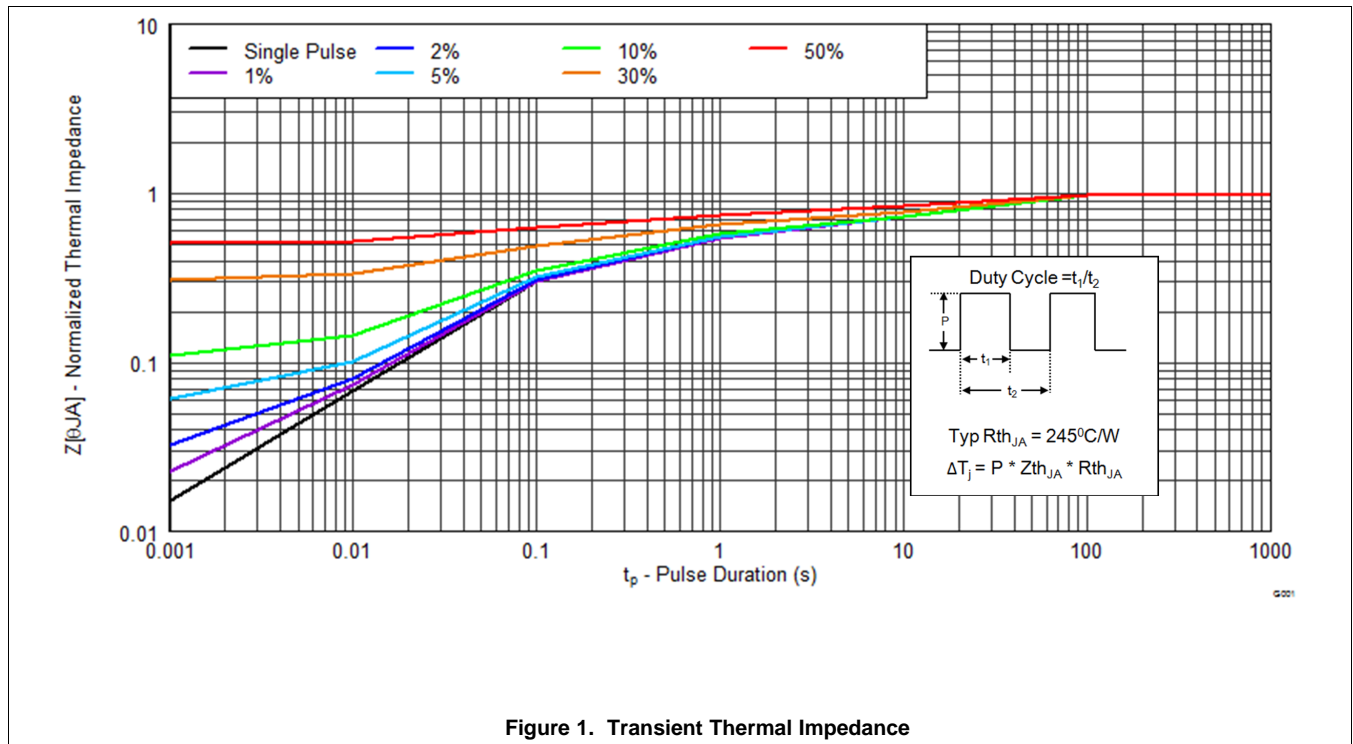
THERMAL METRIC		TYPICAL VALUES	UNIT
R _{θJA}	Junction-to-Ambient Thermal Resistance ⁽¹⁾	85	°C/W
	Junction-to-Ambient Thermal Resistance ⁽²⁾	245	

(1) Device mounted on FR4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu.

(2) Device mounted on FR4 material with minimum Cu mounting area.

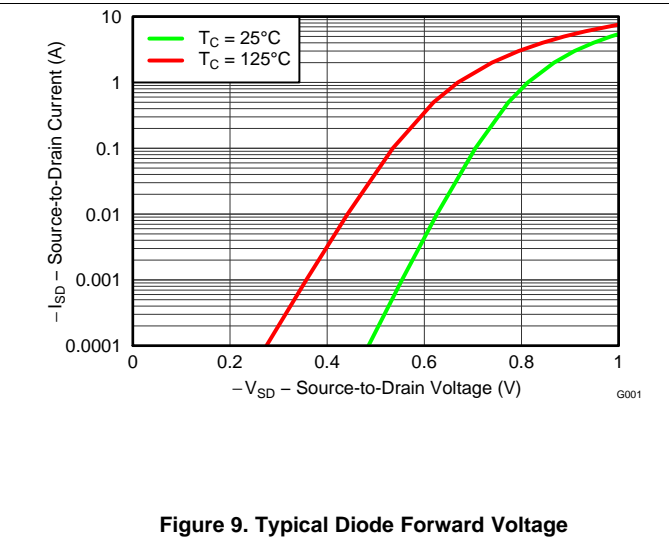
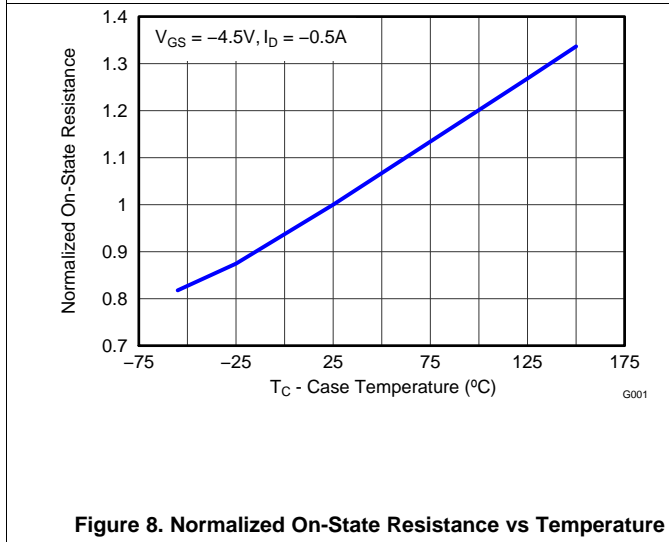
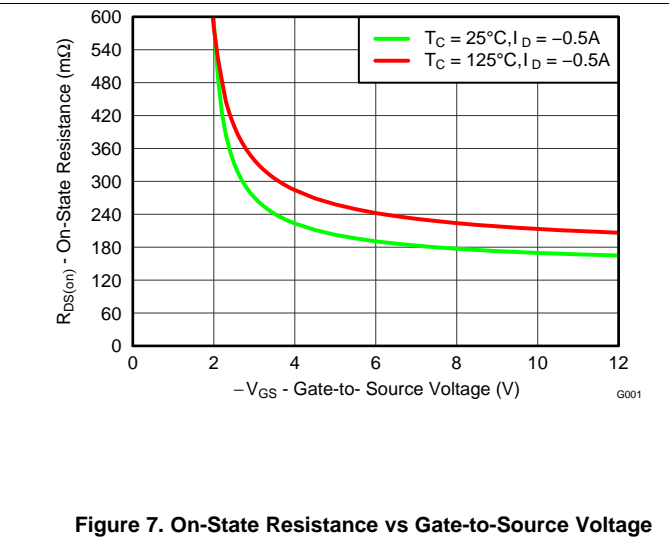
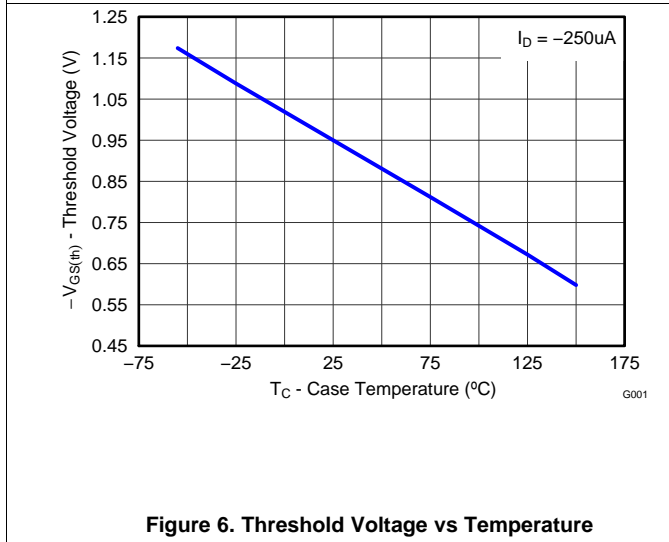
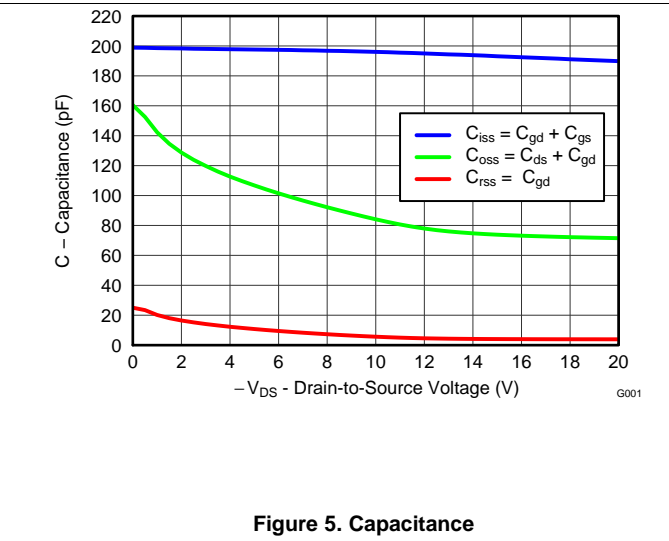
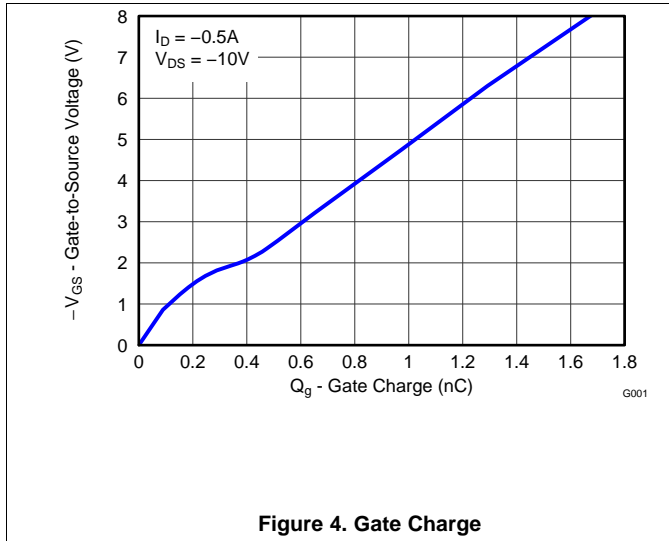
5.3 Typical MOSFET Characteristics

($T_A = 25^\circ\text{C}$ unless otherwise stated)



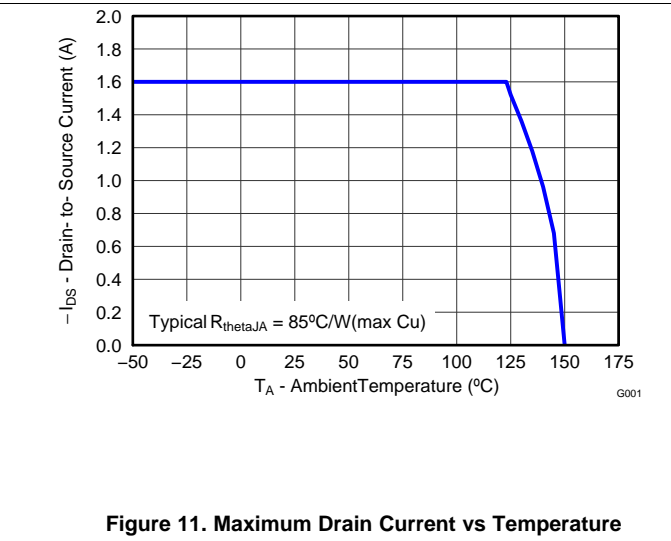
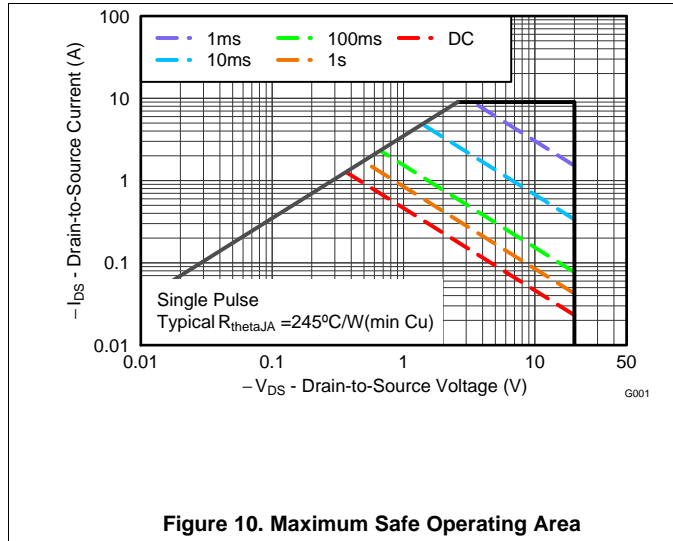
Typical MOSFET Characteristics (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)



Typical MOSFET Characteristics (continued)

($T_A = 25^\circ\text{C}$ unless otherwise stated)



6 Device and Documentation Support

6.1 Trademarks

FemtoFET is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

6.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

6.3 Glossary

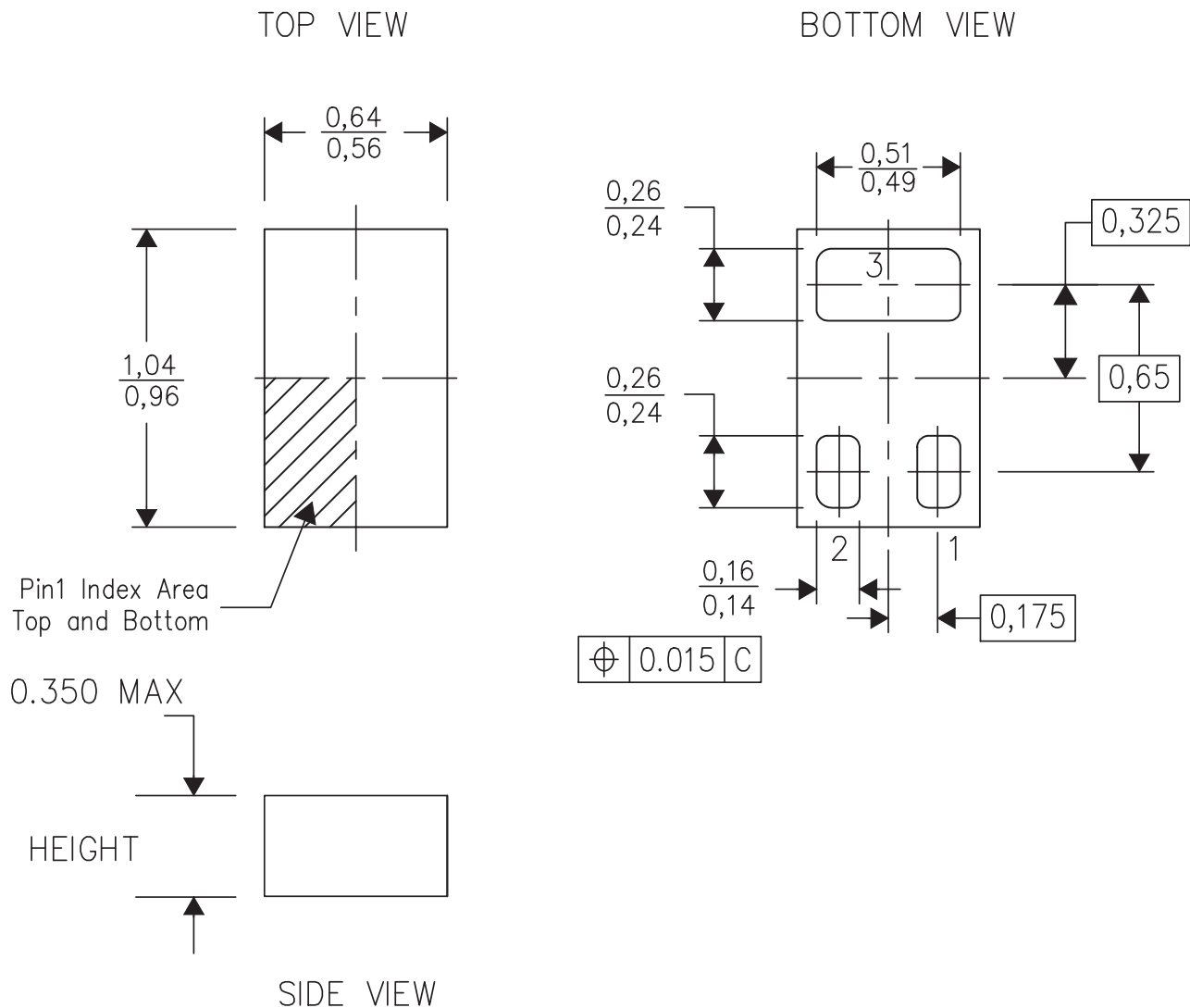
[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

7 Mechanical Data

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

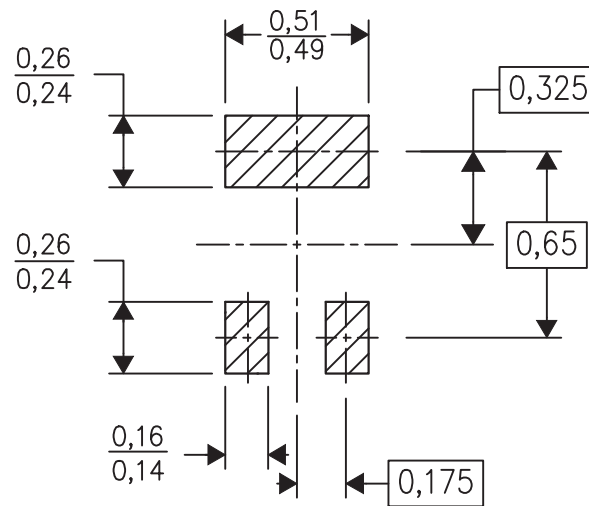
7.1 Mechanical Dimensions



Pin Configuration

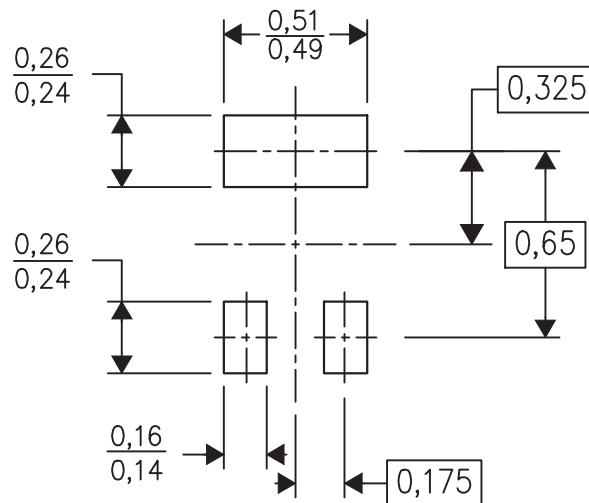
Position	Designation
Pin 1	Gate
Pin 2	Source
Pin 3	Drain

7.2 Recommended Minimum PCB Layout



(1) All dimensions are in millimeters.

7.3 Recommended Stencil Pattern



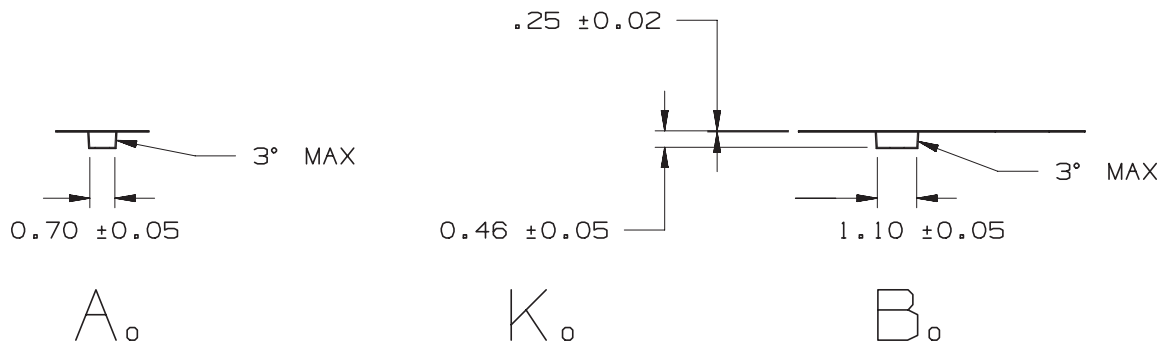
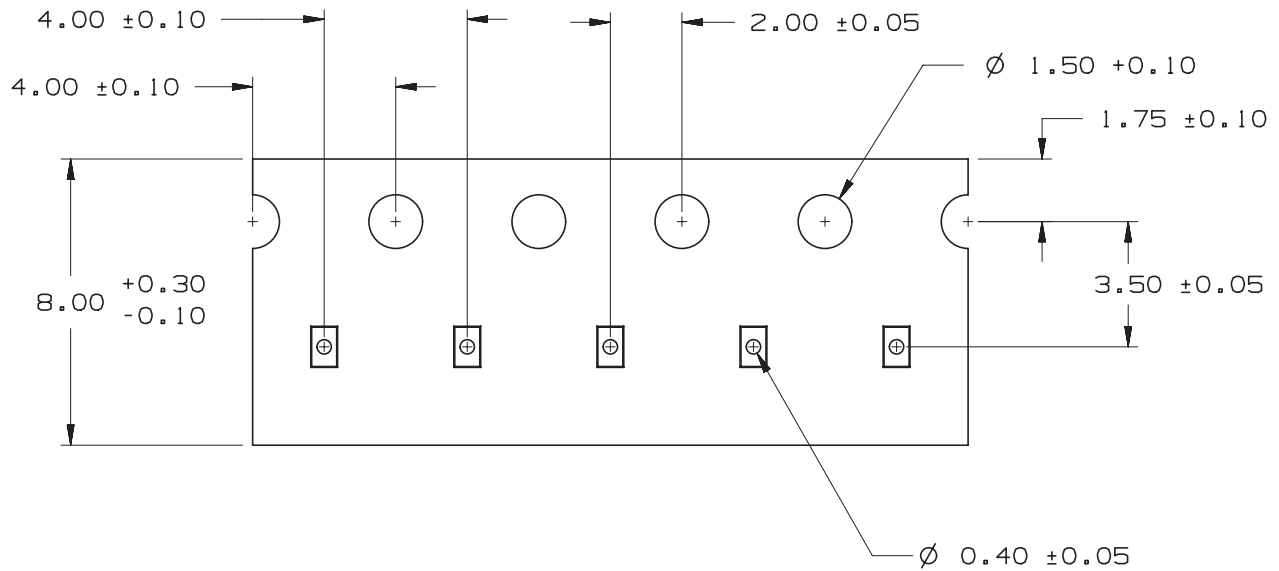
(1) All dimensions are in millimeters.

CSD25483F4

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7.4 CSD25483F4 Embossed Carrier Tape Dimensions



- (1) Pin 1 is oriented in the top-right quadrant of the tape enclosure (quadrant 2), closest to the carrier tape sprocket holes.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CSD25483F4	ACTIVE	PICOSTAR	YJC	3	3000	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM	-55 to 150	DR	Samples
CSD25483F4T	ACTIVE	PICOSTAR	YJC	3	250	Green (RoHS & no Sb/Br)	Call TI	Level-1-260C-UNLIM	-55 to 150	DR	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION



QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD25483F4	PICOST AR	YJC	3	3000	178.0	8.4	0.7	1.1	0.46	4.0	8.0	Q2
CSD25483F4	PICOST AR	YJC	3	3000	180.0	8.4	0.7	1.1	0.46	4.0	8.0	Q2

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD25483F4	PICOSTAR	YJC	3	3000	220.0	220.0	35.0
CSD25483F4	PICOSTAR	YJC	3	3000	182.0	182.0	17.0

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